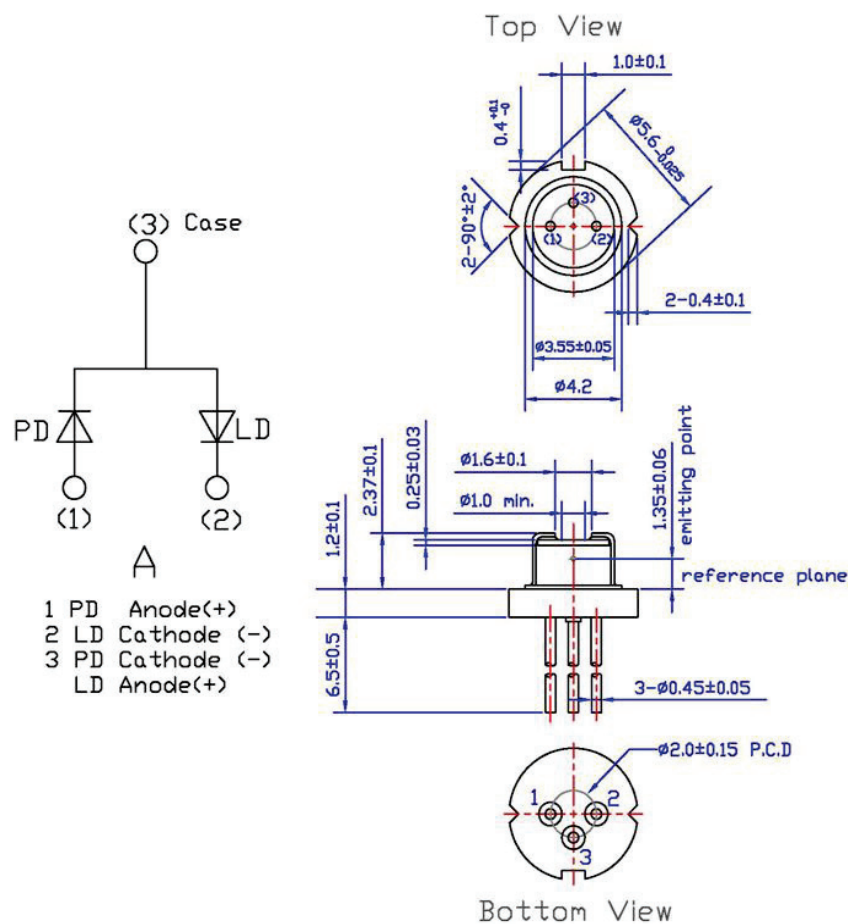


830nm IR Laser Diode LCU83C051A-preliminary

■ Specifications

- (1) Device: Laser Diode
 (2) Structure: TO-18 (ϕ 5.6mm), With Pb free glass cap, PD

■ External dimensions (Unit : mm)



■ Absolute Maximum Ratings (Tc=25°C)

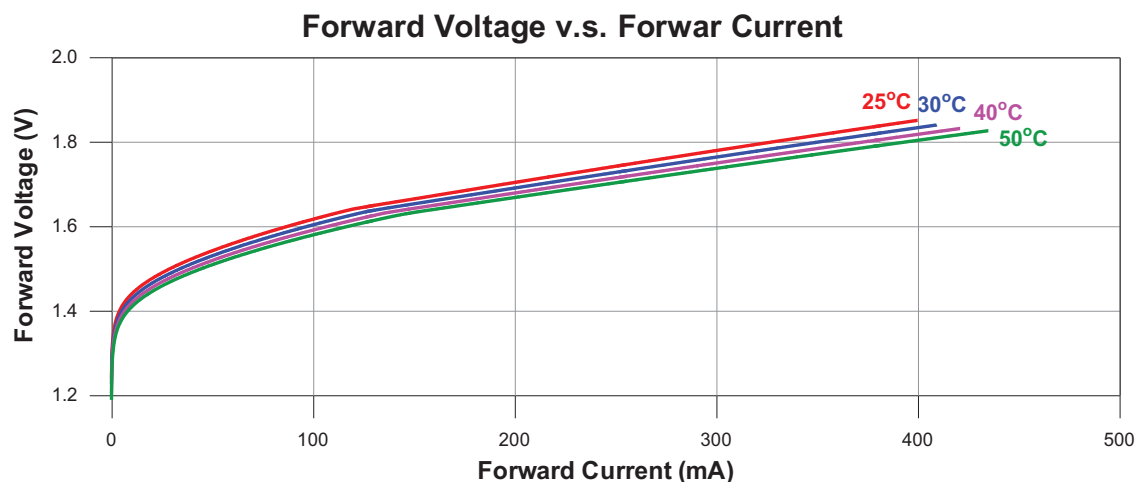
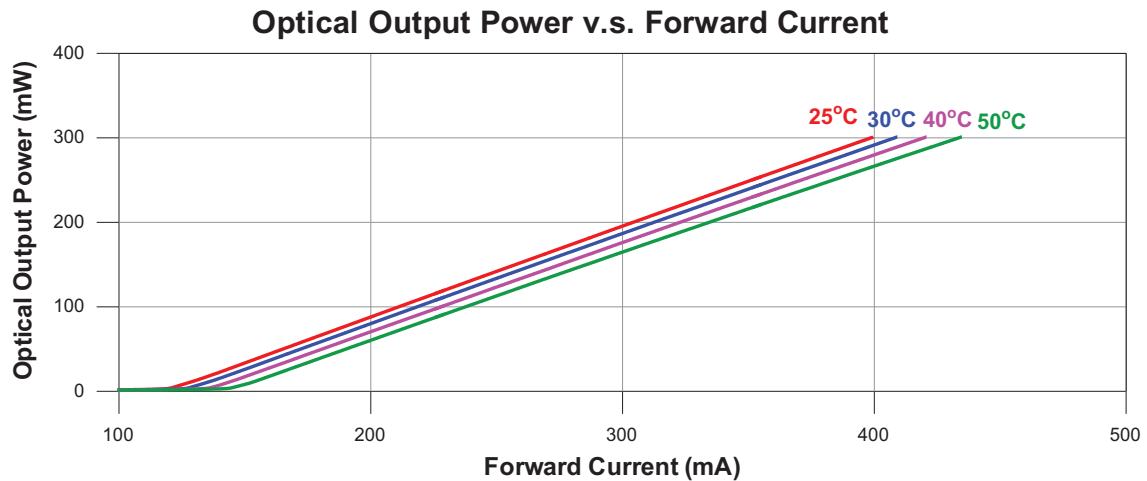
Parameter	Symbols	Ratings	Units
Optical Output	Po	300	mW
Reverse Voltage	Laser	Vr	2
	PIN PD	Vr(PIN)	30
Operating Temperature	Top	-10 ~ +50	°C
Storage Temperature	Tstg	-40 ~ +85	°C

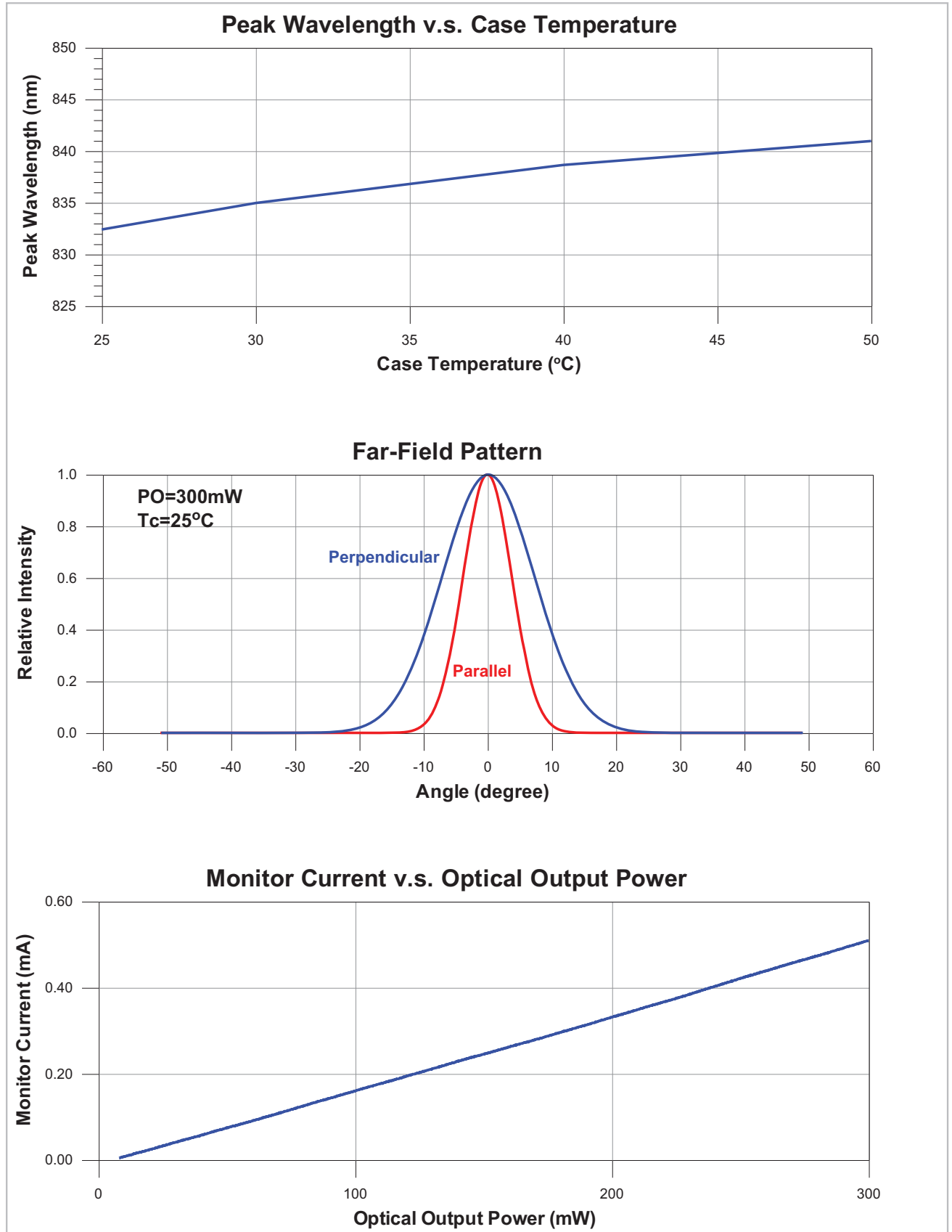
■ Electrical and Optical Characteristics(Tc=25°C)

Parameter	Symbols	Conditions	Min.	Typ.	Max.	Units	
Threshold Current	I _{th}	-	-	115	130	mA	
Operating Current	I _{op}	P _o =300mW	-	410	450	mA	
Operating Voltage	V _{op}	-	-	1.85	2	Volts	
Slope Efficiency	η	225mW-75mW	-	1.0	-	mW/mA	
		I _{225mW} -I _{75mW}					
Monitor Current	I _m	P _o =300mW	0.1	0.5	1	mA	
Beam Divergence (FWHM)	Parallel	θ //	P _o =300mW	-	9	14	deg.
	Perpendicular	θ ⊥	P _o =300mW	-	17	22	deg.
Lasing Wavelength*	λ	P _o =300mW	820	830	840	nm	

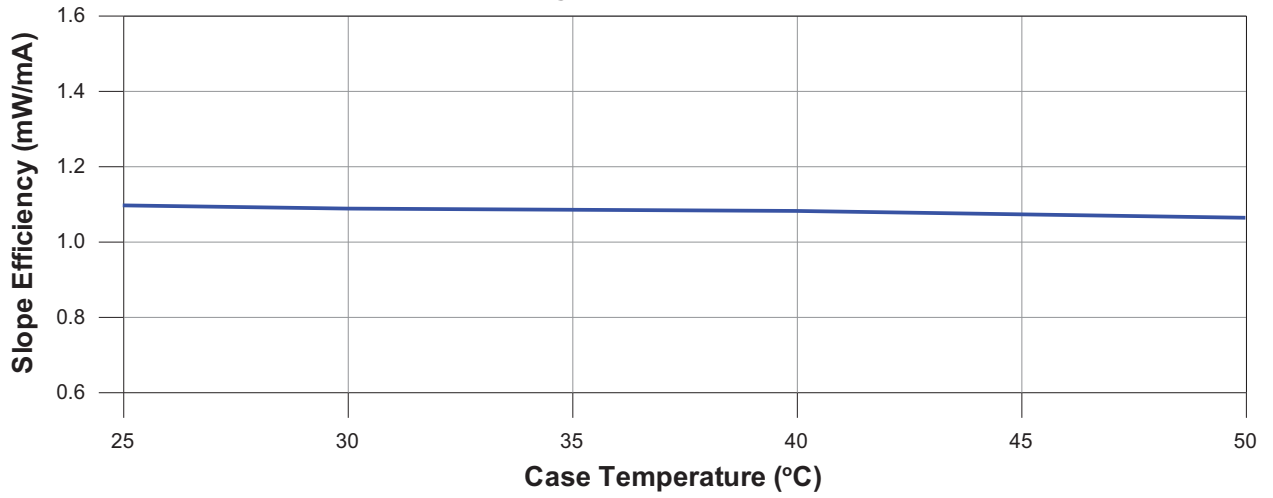
◎θ // and θ ⊥ are defined as the angle within which the intensity is 50% of the peak value.

■ Typical characteristic curves





Slope Efficiency v.s. Case Temperature



Threshold Current v.s. Case Temperature

